

Carbon Monoxide Detector Companion IC

Features:

- · Low Quiescent Current
- · Operation from 2V or 12V
- · 9.8V Boost Regulator
- · Horn Driver
- LED Driver
- 3.3V Regulated Voltage for Microcontroller Operation
- · Internal Operational Amplifiers:
 - ±1 mV Input Offset Voltage
 - Rail-to-rail Input and Output
 - 10 kHz Gain Bandwidth Product
 - Unity Gain Stable
- · Bidirectional Alarm Interconnect

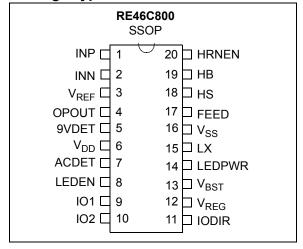
Applications:

- · CO Detector
- · Toxic Gas Detector
- · Heat Detector

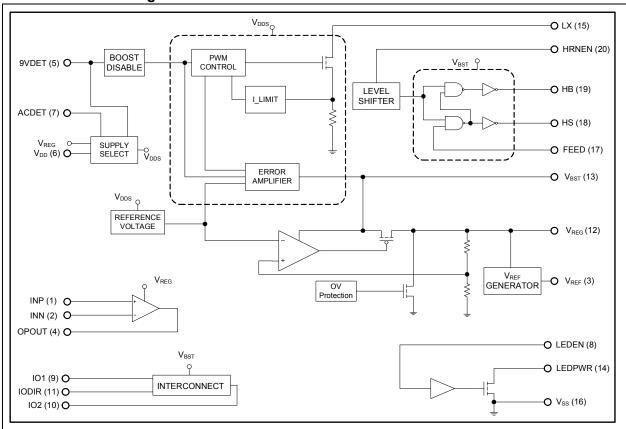
Description:

The RE46C800 is a low-power CMOS carbon monoxide detector companion IC. The RE46C800 provides all of the analog, interface, and power management functions for a microcontroller-based CO or toxic gas detector. It is intended for use in both 3V and 9V battery or battery-backed applications. It features a boost regulator and horn driver circuit suitable for driving a piezoelectric horn, a 3.3V regulator for microcontroller voltage regulation, an LED driver, an operational amplifier and an IO for communication with interconnected units.

Package Types



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

1.1 Absolute Maximum Ratings†

V _{DD}	0.3V to 5.5V
ESD HBM	1500V
ESD MM	150V
V _{BST} , LX	0.3V to 13V
Input Voltage Range Except ACDET, 9VDET, FEED, IO1	$V_{IN1} =3V \text{ to } V_{REG} + .3V$
ACDET, 9VDET Input Voltage Range	$V_{IN2} =3V \text{ to } V_{BST} + .3V$
FEED Input Voltage Range	V _{INFD} = -10V to + 22V
IO1 Input Voltage Range	V _{INIO1} =3 to +15V
Input Current except FEED	I _{IN} = 10 mA
Operating Temperature	$T_A = -10^{\circ}C \text{ to } +60^{\circ}C$
Storage Temperature	T _{STG} = -55°C to +125°C
Maximum Junction Temperature	T _J = +150°C

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS - RE46C800

Unless otherwise indicated, all parameters apply at T_A = -10°C to +60°C, V_{DD} = 3V, V_{SS} = 0V, C_{REG} = 10 μ F, C_{BST} = 10 μ F, 9VDET low, ACDET low. (Note 1) (Note 2) (Note 3)

CBST - 10 pr, 9 VDE1 low, ACDE1 low. (Note 1) (Note 2) (Note 3)									
Parameter	Symbol	Test Pin	Min.	Тур.	Max.	Units	Conditions		
Supply Voltage	V_{DD}	6	2		5	V	Operating		
	V _{BST}	13	6		12	V	Operating, 9V operation, 9VDET or ACDET high		
Standby Supply Current	I _{DDSTBY1}		-	13.6		μA	Inputs low; No loads, boost regulator running (Note 4)		
	I _{DDSTBY2}		1	5.8	9.3	μA	Inputs low; No loads, boost regulator disabled, 9V operation, V _{BST} = 9V, 9VDET high		
Quiescent Supply Current	I _{DDQ}	6	_	6.8	10.3	μA	Inputs low; No loads; V _{BST} = 5V; V _{LX} = 0.5V		
Quiescent I _{VO}	I _{VOQ}	13	_	3.6	5.2	μA	Inputs low; No loads; V _{BST} = 5V; V _{LX} = 0.5V		

- Note 1: Wherever a specific V_{BST} value is listed under test conditions, the V_{BST} is forced externally with the inductor disconnected and the boost regulator is NOT running.
 - 2: Typical values are for design information only.
 - 3: The limits shown are 100% tested at 25°C only. Test limits are guard-banded based on temperature characterization to warrant compliance at temperature extremes.
 - **4:** The Standby Supply Current I_{DDSTBY1} specified above can be approximated as follows:

```
\begin{split} I_{DDSTBY1} &= I_{DDQ} + I_{IND} \\ Where &\quad I_{DDQ} = \text{average current into V}_{DD} \text{ supply} \\ &\quad I_{IND} = \text{average inductor current} = V_{BST} * IVOQ/(V_{IN} * \text{Efficiency}) \\ &\quad V_{IN} = V_{DD} = 3V \end{split}
```

DC ELECTRICAL CHARACTERISTICS - RE46C800 (CONTINUED)

Unless otherwise indicated, all parameters apply at T_A = -10°C to +60°C, V_{DD} = 3V, V_{SS} = 0V, C_{REG} = 10 μ F, C_{BST} = 10 μ F, 9VDET low, ACDET low. (Note 1) (Note 2) (Note 3)

Parameter	Symbol	Test Pin	Min.	Тур.	Max.	Units	Conditions	
Input Leakage Low	I _{IL}	1, 5, 7, 8, 10, 11, 20	_	_	-100	nA	INP, 9VDET, ACDET, LEDEN, IO2, IODIR, HRNEN Inputs $V_{IN} = V_{SS}$	
	I _{ILOP}	2	_	_	-200	pА	INN input, V _{IN} = V _{SS}	
	I _{ILF}	17	_	-15	-50	μA	FEED = -10V, V _{BST} = 10V	
Input Leakage High	I _{IH1}	1, 8, 10, 11, 20	_	_	100	nA	INP, LEDEN, IO2, IODIR, HRNEN Inputs V _{IN} = V _{REG}	
	I _{IH2}	5, 7	_	_	100	nA	9VDET, ACDET Inputs, V _{IN} = V _{BST} , V _{BST} = 10V.	
	I _{IHOP}	2		_	200	pА	INN input, V _{IN} = V _{REG}	
	I _{IHF}	17	_	20	50	μA	FEED = +22V; V _{BST} = 10V	
Output Off Leakage High	I _{IHOZ}	14, 15	_	_	1	μA	LEDEN = V _{SS} , LEDPWR, LX = V _{BST} = 10V	
Input Voltage Low	V _{IL1}	8, 10, 11, 20	_	_	1	V	LEDEN, IO2, IODIR, HRNEN Inputs	
	V _{IL2}	7	_	_	7	V	ACDET Input, V _{BST} = 10V	
	V _{IL3}	5	_	_	4	V	9VDET Input, V _{BST} = 10V	
	V _{ILF}	17	_	_	3	V	FEED Input; V _{BST} = 10V	
	V _{ILIO} 1	9	_	_	8.0	٧	Falling edge of IO1 input, IODIR = V _{SS}	
Input Voltage High	V _{IH1}	8, 10, 11, 20	V _{REG} 7	_	_	V	LEDEN, IO2, IODIR, HRNEN Inputs	
	V _{IH2}	7	8.2	_	_	V	ACDET Input, V _{BST} = 10V	
	V _{IH3}	5	6	_	_	V	9VDET Input, V _{BST} = 10V	
	V_{IHF}	17	7	_	_	V	FEED Input; V _{BST} = 10V	
	V _{IHIO} 1	9	2	_	_	V	Rising edge of IO1 input, IODIR = V _{SS}	
Output Voltage Low	V _{OL1}	18, 19	_	_	0.5	V	HS or HB; I_{OUT} = 16 mA; V_{DD} = 3V; V_{BST} = 10V, HRNEN = V_{SS}	
	V _{OL2}	14	_	_	0.5	V	LEDPWR; I _{OUT} = 10 mA; V _{BST} = 10V	
	V _{OLIO2}	10	_	_	0.5	V	IO2 output, I _{OUT} = 100 μA, IODIR = V _{SS}	

Note 1: Wherever a specific V_{BST} value is listed under test conditions, the V_{BST} is forced externally with the inductor disconnected and the boost regulator is NOT running.

- 2: Typical values are for design information only.
- 3: The limits shown are 100% tested at 25°C only. Test limits are guard-banded based on temperature characterization to warrant compliance at temperature extremes.
- **4:** The Standby Supply Current I_{DDSTBY1} specified above can be approximated as follows:

```
\begin{split} I_{DDSTBY1} &= I_{DDQ} + I_{IND} \\ \text{Where} \quad I_{DDQ} &= \text{average current into V}_{DD} \text{ supply} \\ &\quad I_{IND} = \text{average inductor current} = V_{BST} * IVOQ/(V_{IN} * \text{ Efficiency}) \\ &\quad V_{IN} = V_{DD} = 3V \end{split}
```

DC ELECTRICAL CHARACTERISTICS - RE46C800 (CONTINUED)

Unless otherwise indicated, all parameters apply at T_A = -10°C to +60°C, V_{DD} = 3V, V_{SS} = 0V, C_{REG} = 10 μ F, C_{BST} = 10 μ F, 9VDET low, ACDET low. (Note 1) (Note 2) (Note 3)

Parameter	Symbol	Test Pin	Min.	Тур.	Max.	Units	Conditions
Output Voltage High	V _{OH1}	18, 19	9.5			V	HS or HB; I_{OUT} = -16 mA; V_{BST} = 10V; HRNEN = V_{REG}
	V _{OHIO1}	9	3	_		V	IO1, I _{OUT} = -4 mA, IODIR = V _{IH1} , IO2 = V _{IH1}
	V _{OHIO2}	10	V _{REG} 5	_	l	V	IO2, I _{OUT} = -100 μA, IODIR = V _{SS} , IO1 = V _{IHIO1}
Reference Voltage	V_{REF}	3	_	300	-	mV	
V _{BST} Output Voltage	V _{VO1}	13	9	9.8	10.6	V	V_{DD} = 3V; HRNEN = V_{REG} ; I_{OUT} = 10 mA
	V _{VO2}	13	3.6	4	4.4	V	V_{DD} = 3V; HRNEN = V_{SS} ; I_{OUT} =10 mA
V _{BST} Efficiency	V _{EFF1}		_	85		%	I_{LOAD} =10 mA; V_{DD} =3V; HRNEN = V_{SS}
	V _{EFF2}			75	1	%	I_{LOAD} = 100 μ A; V_{DD} = 3V; HRNEN = V_{SS}
V _{REG} Voltage	V_{REG}	12	3.2	3.3	3.4	V	I _{OUT} < 20 mA
V _{REG} Load Regulation	V _{REGLD}	12	_	30	50	mV	I _{OUT} = 0 to 20 mA; HRNEN = V _{REG}
Brown-out Threshold	V _{OBVT}	13	3.2	3.6	4	V	Falling edge of V _{BST}
V _{BST} -to-Brown-out Margin	V _{OBVTM}	13	100	400	ı	mV	V _{VO2} - V _{OBVT}
Brown-out Pull Down	I _{BT}	12	20	40	1	mA	$V_{BST} = 3.0V; V_{REG} = 2.0V$
V _{REG} Over Voltage Clamp	V _{CL}	12	3.75	4	4.25	V	
IO1 Output Current	IO1 _{IH1}	9	25		60	μΑ	IODIR = V _{SS} , IO1 = 1V
	IO1 _{IH2}	9		_	150	μΑ	IODIR = V _{SS} , IO1 = 15V
	IO1 _{IOH1}	9	-4	-5		mA	IODIR, IO2 = V _{IH1} , IO1 = 3V
	IO1 _{IOH2}	9		-5	-16	mA	IODIR, IO2 = V_{IH1} , IO1 = V_{SS}
	IO1 _{IOL1}	9	_	10	_	mA	IO Dump Current, IODIR = V _{IH1} , IO2 = V _{SS} , IO1 = 1V
IO1 Hysteresis	V _{HYSTIO1}	9	_	150		mV	IODIR = V _{SS}
Op Amp							
Input Offset Voltage	Vos	4	-1		1	mV	V _{CM} = 0.3V
Common Mode Input Range	V _{CMR}	1, 2	VSS	_	V_{REG}	V	

Note 1: Wherever a specific V_{BST} value is listed under test conditions, the V_{BST} is forced externally with the inductor disconnected and the boost regulator is NOT running.

- 2: Typical values are for design information only.
- 3: The limits shown are 100% tested at 25°C only. Test limits are guard-banded based on temperature characterization to warrant compliance at temperature extremes.
- **4:** The Standby Supply Current I_{DDSTBY1} specified above can be approximated as follows:

 $I_{DDSTBY1} = I_{DDQ} + I_{IND}$

Where I_{DDQ} = average current into V_{DD} supply

 I_{IND} = average inductor current = V_{BST} * IVOQ/(V_{IN} * Efficiency)

 $V_{IN} = V_{DD} = 3V$

DC ELECTRICAL CHARACTERISTICS - RE46C800 (CONTINUED)

Unless otherwise indicated, all parameters apply at T_A = -10°C to +60°C, V_{DD} = 3V, V_{SS} = 0V, C_{REG} = 10 μ F, C_{BST} = 10 μ F, 9VDET low, ACDET low. (Note 1) (Note 2) (Note 3)

Parameter	Symbol	Test Pin	Min.	Тур.	Max.	Units	Conditions
Common Mode Rejection Ratio	CMRR	1, 2, 4	_	80	_	dB	V_{REG} = 3.3V, VCM = -0.3V to 3.3V
DC Open-Loop Gain (large signal)	A _{OL}	4	_	115	_	dB	RL = 50 k Ω , V _{OUT} = 0.3V to V _{REG} - 0.3V
Maximum Output Voltage Swing	V_{OL}, V_{OH}	4	V _{SS} +10	_	V _{REG} -10	mV	RL = 50 k Ω , 0.5V input overdrive
Output Short Circuit Current	I _{SC}	4	_	20	_	mA	V _{REG} = 3.3V

- Note 1: Wherever a specific V_{BST} value is listed under test conditions, the V_{BST} is forced externally with the inductor disconnected and the boost regulator is NOT running.
 - 2: Typical values are for design information only.
 - 3: The limits shown are 100% tested at 25°C only. Test limits are guard-banded based on temperature characterization to warrant compliance at temperature extremes.
 - **4:** The Standby Supply Current I_{DDSTBY1} specified above can be approximated as follows:

$$I_{DDSTBY1} = I_{DDQ} + I_{IND}$$

Where I_{DDQ} = average current into V_{DD} supply

 I_{IND} = average inductor current = $V_{BST} * IVOQ/(V_{IN} * Efficiency)$

 $V_{IN} = V_{DD} = 3V$

AC ELECTRICAL CHARACTERISTICS

Unless otherwise indicated, all parameters apply at T_A = -10°C to +60°C, V_{DD} = 3V, V_{SS} = 0V, C_{REG} = 10 μ F, $C_{VBST} = 10 \mu F$. **Test Pin** Parameter **Symbol** Min. Тур. Max. Units **Conditions OP Amp AC Response** Gain Bandwidth **GBWP** 4 10 kHz Product Slew Rate 3 SR 4 V/ms Phase margin PM4 65 G = +1V/V**Op Amp Noise** Input Voltage f = 0.1 Hz to 10 kHz 1, 2 5 μV_{P-P} Eni Noise Input Voltage 1, 2 170 nV/ f = 1 kHz $e_{ni} \\$ Noise Density √Hz Input Current 1, 2 0.6 fA/ f = 1 kHzi_{ni} Noise Density √Hz

Note 1: Wherever a specific V_{BST} value is listed under test conditions, the V_{BST} is forced externally with the inductor disconnected and the boost regulator is NOT running.

- 2: Typical values are for design information only.
- 3: The limits shown are 100% tested at 25°C only. Test limits are guard-banded based on temperature characterization to warrant compliance at temperature extremes.

TEMPERATURE CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V _{DD} = 3V, V _{SS} = 0V								
Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions		
Temperature Ranges	Temperature Ranges							
Operating Temperature Range	T _A	-10	_	60	°C			
Storage Temperature Range	T _{STG}	-55	_	125	°C			
Thermal Package Resistances								
Thermal Resistance, 20L-SSOP	θ_{JA}	_	87.3	_	°C/W			

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: PIN FUNCTION TABLE

RE46C800	Cumah al	Description
SSOP	Symbol	Description
1	INP	Non-inverting input of the op amp.
2	INN	Inverting input of the op amp.
3	V_{REF}	Voltage reference for CO biasing and detection circuitry.
4	OPOUT	Output of the op amp.
5	9VDET	Logic input used to disable the boost regulator.
6	V_{DD}	Low-voltage supply input.
7	ACDET	AC power detect pin.
8	LEDEN	Logic input used to enable the LED driver. Input is designed to interface with circuitry supplied by V_{REG} , so input voltage levels will scale with the V_{REG} voltage.
9	IO1	Logic bidirectional pin used for connection to remote units. This pin has an internal pull-down device. If used as an output, high level is VVO1.
10	IO2	Bidirectional pin used to send and receive IO1 interconnect signal status.
11	IODIR	Logic input used to select IO direction.
12	V_{REG}	Regulated output voltage. Nominal output is 3.3V.
13	V _{BST}	Boost regulator output, typically output voltage is 4V or 9.8V. Also used as the high-voltage supply input.
14	LEDPWR	Open drain NMOS output used to drive a visible LED.
15	LX	Open drain NMOS output used to drive the boost regulator inductor. The inductor should be connected from this pin to the positive supply through a low resistance path.
16	V_{SS}	Connect to the negative supply voltage.
17	FEED	Usually connected to the feedback electrode of the piezoelectric horn through a current limiting resistor. If not used, this pin must be connected to $V_{\rm SS}$.
18	HS	HS is a complementary output to HB and connects to the ceramic electrode (S) of the piezoelectric transducer.
19	НВ	This pin is connected to the metal electrode (B) of a piezoelectric transducer.
20	HRNEN	Logic input for horn enable designed to interface with circuitry supplied by V_{REG} . Input voltage levels will scale with the V_{REG} voltage.

3.0 DEVICE DESCRIPTION

3.1 Introduction

The RE46C800 provides the necessary analog functions to build a microcontroller-based CO or toxic gas detector. This includes an op amp and voltage reference for the electrochemical sensor, a voltage regulator for the microcontroller, an LED driver, a horn driver, a detector interconnect function, a boost regulator for 3V operation, a power management system that allows operation from 3V, 9V or AC derived power. The power management system provides the capability for AC power with battery backup. The RE46C800 provides a simple means for the microcontroller to control the operation of the CO detector and provide the necessary signaling functions during an alarm condition.

3.2 CO Sensor Circuit

The RE46C800 provides a low offset op amp and reference voltage, $V_{\rm REF}$, for a two terminal electrochemical CO or toxic gas sensor. The unity gain stable op amp provides rail-to-rail inputs and output. The op amp output is monitored by the microcontroller to determine the CO concentration. This uncommitted op amp can be used for other purposes such as temperature sensing.

3.3 Power Management System

The power management system allows the RE46C800 to be powered from a 3V or 9V battery or AC power. AC power is supplied as a DC voltage derived from an AC power supply. This DC voltage is diode connected to the V_{BST} pin of the RE46C800. AC supplied power and a 9V battery can both be diode connected to the V_{BST} pin.

For low-voltage systems the battery is connected to the V_{DD} pin. When only a low-voltage battery is available, the internal circuitry is powered from V_{DD} . When a 9V battery or AC power is available, the internal circuitry is powered from V_{REG} , which is a regulated 3.3V. The selection of the power source for the internal circuitry is controlled with the ACDET pin when the 9VDET pin is low

In low-voltage systems that are also AC powered, the boost regulator will turn on if voltage of the AC supplied power drops below the specified boost regulator voltage. This can cause the low-voltage battery to discharge more rapidly than expected.

The 9VDET pin will disable the boost regulator if 9VDET is high. For a low-voltage system, the 9VDET pin should be connected to V_{SS} which will enable the boost regulator.

Table 3-1 shows the truth table for the power management system.

TABLE 3-1: POWER MANAGEMENT SYSTEM

9VDET	ACDET	Internal Supply	Boost Regulator
0	0	V_{DD}	Enabled
0	1	V_{REG}	Enabled
1	0	V_{REG}	Disabled
1	1	V_{REG}	Disabled

3.4 Boost Regulator

The boost regulator only operates in low-voltage applications. The boost regulator is a fixed off time boost regulator with peak current limiting. In low-boost operation the peak current is nominally 0.6A. In high-boost operation the peak current is nominally 1.2A. The boost regulator normally operates in Low-Boost mode, which provides a nominal 4V output voltage on the $V_{\rm BST}$ pin. In High-Boost mode, the boost regulator provides a nominal 9.8V on the $V_{\rm BST}$ pin. The boost regulator can be placed in High-Boost mode with HORNEN, LEDEN, or IODIR and IO2 both asserted high.

The brown-out threshold voltage is the V_{BST} voltage at which the voltage regulator and the horn will be disabled. When the V_{BST} voltage falls below the brown-out threshold voltage of 3.6V, V_{REG} will be disabled and pulled to V_{SS} with a nominal 40 mA current. When the boost voltage rises above the brown-out threshold voltage, V_{REG} is enabled.

3.5 Voltage Regulator

The voltage regulator provides a nominal 3.3V output at the V_{REG} pin and is intended to power a microcontroller. In normal operation, the regulator will source current up to 20 mA, but the current sinking capability is typically under 1 μA . The voltage regulator is powered from the V_{BST} pin. In low-voltage applications the regulator is powered by the boost regulator and the regulator load current is part of the boost regulator load current. An overvoltage clamp is intended to limit the voltage at V_{REG} if it is pulled up by an external source to greater than 4V. When the boost regulator experiences a brown-out condition, the voltage regulator will be disabled and the V_{REG} output will be pulled to V_{SS} .

3.6 LED Driver

The LED drive circuit provides power to an LED, which can be used as a visual indicator by the system. The LED drive circuit can also be used as part of a battery check function in battery-powered applications. When LEDEN is asserted high the LED will load the V_{BST} output and the microcontroller can monitor the battery operation under load. In low-voltage systems the boost regulator will be placed into high-boost operation when LEDEN is asserted high. The load current is set by the resistor in series with the LED.

3.7 Interconnect Operation

The IO circuitry provides the means for the CO detector to be connected to other CO detectors or smoke alarms. Table 3-2 below provides the truth table for the interconnect circuit operation. IO1 is a bidirectional pin that connects to other CO detectors or smoke alarms. IO2 is a bidirectional pin that connects to the microcontroller. IODIR connects to the microcontroller and determines when IO1 and IO2 act as an input or output. When IO1 is used as an output asserting a logic high, the IO1 output acts as current source that is biased from $V_{\rm BST}$. In low-voltage applications where the boost regulator is enabled, the boost regulator will operate in High-Boost mode. When IO1 is used as an output asserting a logic low, the IO1 output acts as current sink. IO2 logic levels are referenced to $V_{\rm REG}$

TABLE 3-2: INTERCONNECT LOGIC TRUTH TABLE

IODIR	IC)2	IO1			
IODIK	Input	Output	Input	Output		
1	0	_	_	0		
1	1	_	_	1		
0	_	0	0	_		
0	_	1	1			

4.0 APPLICATION NOTES

4.1 Boost Regulator

The boost regulator in High-Boost mode (nominal V_{BST} = 9.8V) can draw current pulses of greater than 1A and is, therefore, very sensitive to series resistance. Critical components of this resistance are: the inductor DC resistance, the internal resistance of the battery and the resistance in the connections from the inductor to the battery, from the inductor to the LX pin, from the inductor through the boost capacitor, and from the V_{SS} pin to the battery. In order to function properly under full load at V_{DD} = 2V, the total of the inductor and interconnect resistances should not exceed 0.3Ω . The internal battery resistance should be no more than 0.5Ω and a low ESR capacitor of 10 µF or more should be connected in parallel with the battery to average the current draw over the boost regulator switching cycle. The Schottky diode and inductor should be specified with a maximum operating current of 1.5A or higher. The boost capacitor should have a low ESR.

4.2 Typical Applications

A few typical applications using the RE46C800 are listed below:

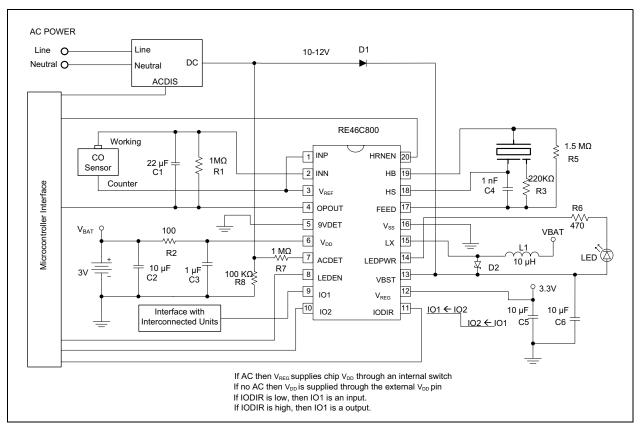


FIGURE 4-1: Typical Application: AC with 3V Battery Backup.

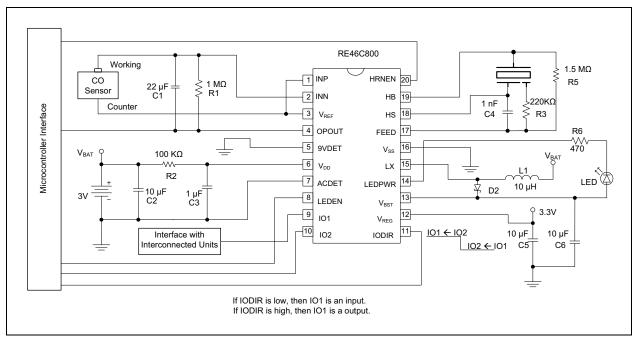


FIGURE 4-2: Typical Application: 3V Battery Operation.

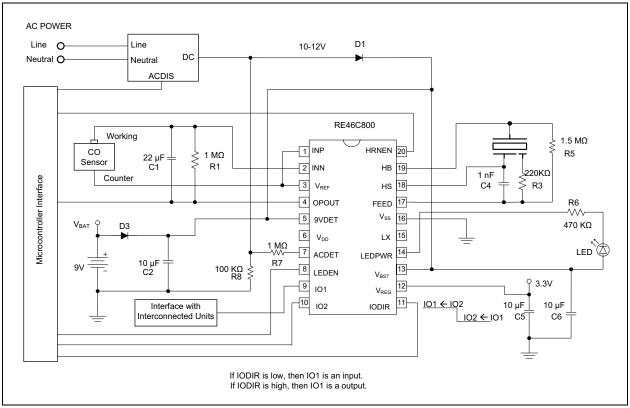


FIGURE 4-3: Typical Application: AC with 9V Battery Backup.

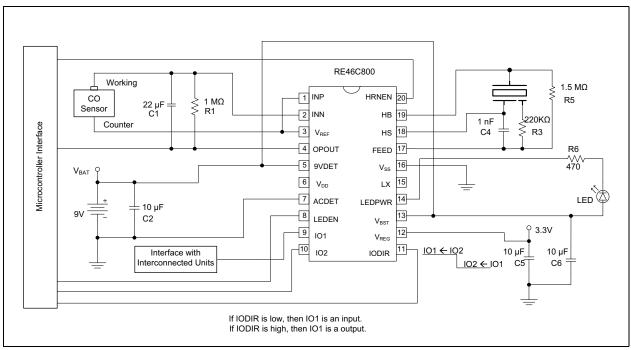


FIGURE 4-4: Typical Application: 9V Battery Operation.

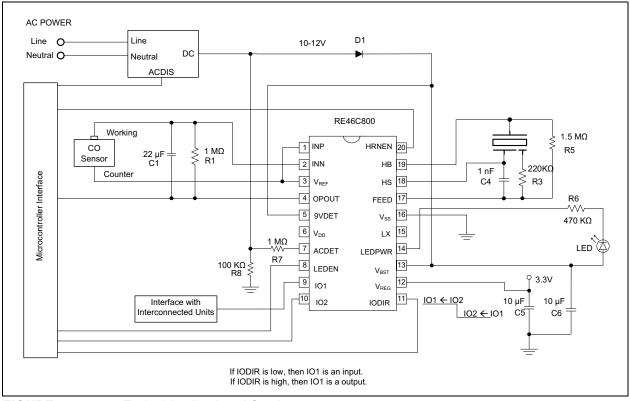


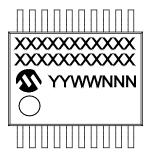
FIGURE 4-5: Typical Application: AC only.

NOTES:

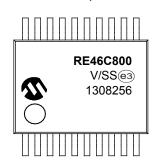
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

20-Lead SSOP (5.30 mm)



Example



Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

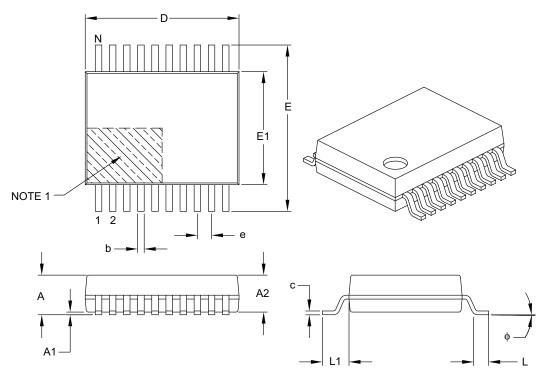
can be really on the eater pastaging for and pastage.

In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

Note:

20-Lead Plastic Shrink Small Outline (SS) - 5.30 mm Body [SSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dime	ension Limits	MIN	NOM	MAX
Number of Pins	N		20	
Pitch	е		0.65 BSC	
Overall Height	А	-	_	2.00
Molded Package Thickness	A2	1.65	1.75	1.85
Standoff	A1	0.05	_	_
Overall Width	E	7.40	7.80	8.20
Molded Package Width	E1	5.00	5.30	5.60
Overall Length	D	6.90	7.20	7.50
Foot Length	L	0.55	0.75	0.95
Footprint	L1	1.25 REF		
Lead Thickness	С	0.09	_	0.25
Foot Angle	ф	0°	4°	8°
Lead Width	b	0.22	_	0.38

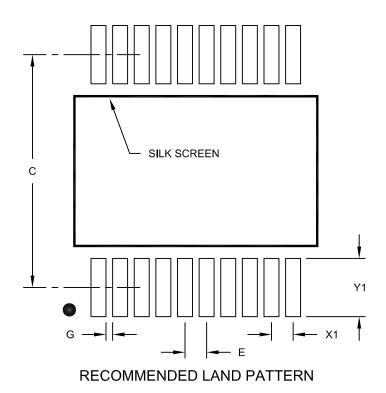
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.20 mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-072B

20-Lead Plastic Shrink Small Outline (SS) - 5.30 mm Body [SSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits			MAX
Contact Pitch	Е	0.65 BSC		
Contact Pad Spacing	С		7.20	
Contact Pad Width (X20)	X1			0.45
Contact Pad Length (X20)	Y1			1.75
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2072A

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (March 2013)

• Initial Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. Examples: RE46C800SS20F: 20LD SSOP package Device Package Number Lead Free/ RE46C800SS20TF: 20LD SSOP package of Pins Tape and Reel Tape and Reel Device: RE46C800 CMOS Carbon Monoxide Detector IC RE46C800T CMOS Carbon Monoxide Detector IC (Tape and Reel) Package: SS20 = Plastic Shrink Small Outline - Narrow, 5.33 mm Body, 20-Lead (SSOP)

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our
 knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data
 Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- · Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PIC³² logo, rfPIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

FilterLab, Hampshire, HI-TECH C, Linear Active Thermistor, MTP, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

Analog-for-the-Digital Age, Application Maestro, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, HI-TIDE, In-Circuit Serial Programming, ICSP, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, mTouch, Omniscient Code Generation, PICC, PICC-18, PICDEM, PICDEM.net, PICkit, PICtail, REAL ICE, rfLAB, Select Mode, SQI, Serial Quad I/O, Total Endurance, TSHARC, UniWinDriver, WiperLock, ZENA and Z-Scale are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

GestIC and ULPP are registered trademarks of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2013, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

ISBN: 9781620771143

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd.

Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support:

http://www.microchip.com/

support Web Address:

www.microchip.com

Atlanta

Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit

Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Indianapolis Noblesville, IN Tel: 317-773-8323

Fax: 317-773-5453

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara

Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto

Mississauga, Ontario,

Canada

Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office

Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong

Tel: 852-2401-1200 Fax: 852-2401-3431

Australia - Sydney Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Hangzhou Tel: 86-571-2819-3187 Fax: 86-571-2819-3189

China - Hong Kong SAR Tel: 852-2943-5100

Fax: 852-2401-3431 China - Nanjing

Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen Tel: 86-755-8864-2200 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Xiamen Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore

Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi

Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune

Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

Japan - Osaka Tel: 81-6-6152-7160

Fax: 81-6-6152-9310 Japan - Tokyo

Tel: 81-3-6880- 3770 Fax: 81-3-6880-3771

Korea - Daegu Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or

82-2-558-5934

Malaysia - Kuala Lumpur

Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung Tel: 886-7-213-7828 Fax: 886-7-330-9305

Taiwan - Taipei Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels

Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen

Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris

Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

UK - Wokingham Tel: 44-118-921-5869 Fax: 44-118-921-5820

11/29/12